NSN 5961-01-072-4078

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-072-4078 **Inclosure Material:** Ceramic **Overall Length:** 0.870 inches **Terminal Length:** 0.145 inches **Overall Height:** 0.200 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 7 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 collector to base voltage/static/emitter open all transistor and 16.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current all transistor and 100.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 750.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Common emitter; transistor junction patter arrangements: npn **Test Data Document:** 96214-803895 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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